## NSN 5961-01-168-6006

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View Online at https://aerobasegroup.com/nsn/5961-01-168-6006

Inclosure Material:

Metal

**Overall Length:** 

1.253 inches

**Function For Which Designed:** 

Voltage regulator

**End Application:** 

4935-01-145-4371; helicopter advance attack, ah-1w; missile, air-to-air, phoenix (aim-54); ticonderoga class cg (47); aircraft, hawkeye e-2c; aircraft, (ac-130-h, mc-130h, ec-130e, hc-130); teletykpe, model 28; spruance cl

**Mounting Facility Quantity:** 

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-4

**Mounting Method:** 

Threaded stud

**Features Provided:** 

Hermetically sealed case

**Overall Width Across Flats:** 

0.505 inches

**Thread Size:** 

0.190 inches

**Criticality Code Justification:** 

Feat

**Semiconductor Material:** 

Silicon

Voltage Rating In Volts Per Characteristic:

15.0 regulator voltage

**Current Rating Per Characteristic:** 

170.00 milliamperes source cutoff current horsepower metric

**Power Rating Per Characteristic:** 

10.0 watts small-signal input power, common-collector preset

**Maximum Operating Tempurature Per Measurement Point:** 

175.0 degrees celsius junction

**Special Features:** 

Weapon system essential; junction patten arrangement: pn

**Test Data Document:** 

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

**Thread Series Designator:** 

Unf

Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

Shelf Life:

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Demilitarization:

No

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